

MOSFETs Silicon N-channel MOS (U-MOSIX-H)

XPH1R104PC

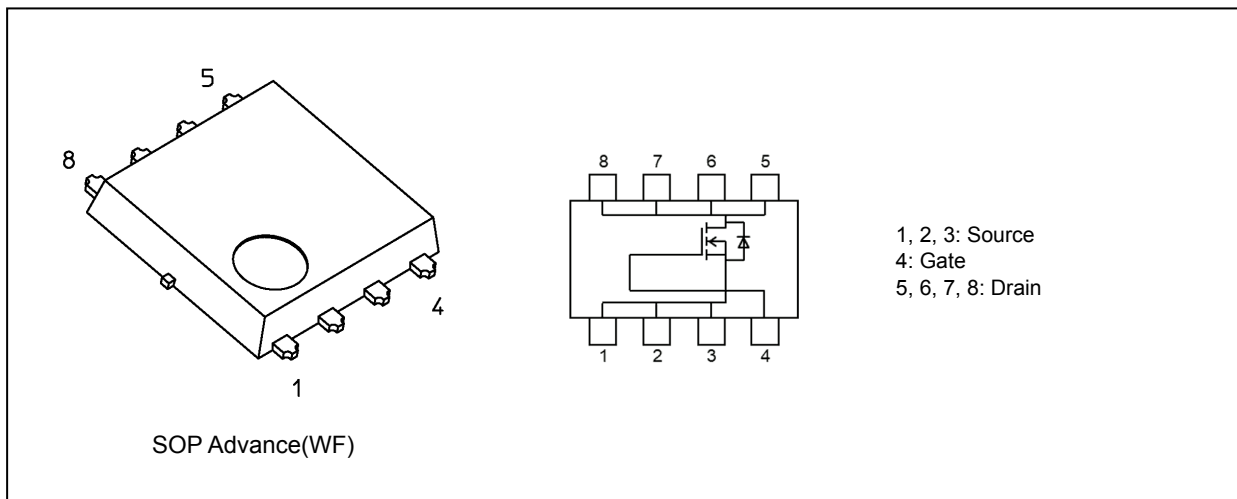
1. Applications

- Automotive
- DC-DC Converters
- Switching Voltage Regulators

2. Features

- (1) AEC-Q101 qualified
- (2) Small, thin package
- (3) Low drain-source on-resistance: $R_{DS(ON)} = 0.95 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (4) Low leakage current: $I_{DSS} = 10 \text{ }\mu\text{A}$ (max) ($V_{DS} = 40 \text{ V}$)
- (5) Enhancement mode: $V_{th} = 1.4 \text{ to } 2.4 \text{ V}$ ($V_{DS} = 10 \text{ V}$, $I_D = 0.5 \text{ mA}$)

3. Packaging and Internal Circuit



Start of commercial production

2026-06

4. Absolute Maximum Ratings (Note) ($T_a = 25\text{ °C}$ unless otherwise specified)

| Characteristics | Symbol | Rating | Unit |
|--|-----------|------------|------|
| Drain-source voltage | V_{DSS} | 40 | V |
| Gate-source voltage | V_{GSS} | ± 16 | |
| Drain current (DC) (Note 1) | I_D | 120 | A |
| Drain current (pulsed) (Note 1) | I_{DP} | 360 | |
| Power dissipation ($T_c = 25\text{ °C}$) | P_D | 132 | W |
| Power dissipation ($t = 10\text{ s}$) (Note 2) | | 3.0 | |
| Power dissipation ($t = 10\text{ s}$) (Note 3) | | 0.96 | |
| Single-pulse avalanche energy (Note 4) | E_{AS} | 140 | mJ |
| Single-pulse avalanche current | I_{AS} | 120 | A |
| Channel temperature (Note 5) | T_{ch} | 175 | °C |
| Storage temperature (Note 5) | T_{stg} | -55 to 175 | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|---|----------------|------|------|
| Channel-to-case thermal impedance ($T_c = 25\text{ °C}$) | $Z_{th(ch-c)}$ | 1.13 | °C/W |
| Channel-to-ambient thermal impedance ($t = 10\text{ s}$) (Note 2) | $Z_{th(ch-a)}$ | 50 | |
| Channel-to-ambient thermal impedance ($t = 10\text{ s}$) (Note 3) | $Z_{th(ch-a)}$ | 156 | |

Note 1: Ensure that the channel temperature does not exceed 175 °C.

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: $V_{DD} = 32\text{ V}$, $T_{ch} = 25\text{ °C}$ (initial), $L = 7.47\text{ }\mu\text{H}$, $R_G = 25\text{ }\Omega$, $I_{AS} = 120\text{ A}$

Note 5: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.



Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

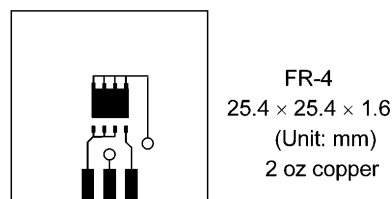


Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------|---------------|---|-----|------|---------|------------------|
| Gate leakage current | I_{GSS} | $V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$ | — | — | ± 1 | μA |
| Drain cut-off current | I_{DSS} | $V_{DS} = 40\text{ V}, V_{GS} = 0\text{ V}$ | — | — | 10 | |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$ | 40 | — | — | V |
| | $V_{(BR)DSX}$ | $I_D = 10\text{ mA}, V_{GS} = -16\text{ V}$ | 24 | — | — | |
| Gate threshold voltage | V_{th} | $V_{DS} = 10\text{ V}, I_D = 0.5\text{ mA}$ | 1.4 | — | 2.4 | |
| Drain-source on-resistance | $R_{DS(ON)}$ | $V_{GS} = 4.5\text{ V}, I_D = 60\text{ A}$ | — | 1.32 | 2.00 | $\text{m}\Omega$ |
| | | $V_{GS} = 10\text{ V}, I_D = 60\text{ A}$ | — | 0.95 | 1.14 | |

6.2. Dynamic Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------|-----------|---|-----|------|------|-------------|
| Input capacitance | C_{iss} | $V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 300\text{ kHz}$ | — | 5400 | 7020 | pF |
| Reverse transfer capacitance | C_{rss} | | — | 320 | 580 | |
| Output capacitance | C_{oss} | | — | 2700 | — | |
| Gate resistance | r_g | | — | 2.1 | 4.2 | Ω |
| Switching time (rise time) | t_r | See Fig. 6.2.1 | — | 8 | — | ns |
| Switching time (turn-on time) | t_{on} | | — | 22 | — | |
| Switching time (fall time) | t_f | | — | 24 | — | |
| Switching time (turn-off time) | t_{off} | | — | 88 | — | |

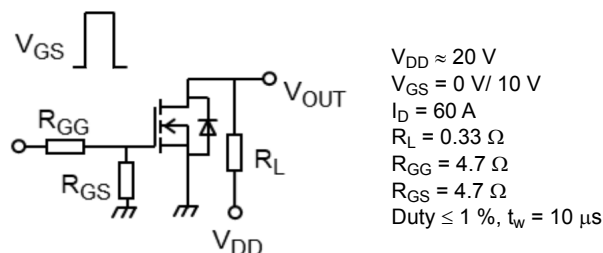


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|--|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Q_g | $V_{DD} \approx 32\text{ V}, V_{GS} = 10\text{ V}, I_D = 120\text{ A}$ | — | 79 | — | nC |
| Gate-source charge 1 | Q_{gs1} | | — | 21 | — | |
| Gate-drain charge | Q_{gd} | | — | 17 | — | |

6.4. Source-Drain Characteristics ($T_a = 25\text{ }^\circ\text{C}$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|--|-----|------|------|------|
| Reverse drain current (DC) (Note 6) | I_{DR} | — | — | — | 120 | A |
| Reverse drain current (pulsed) (Note 6) | I_{DRP} | — | — | — | 360 | A |
| Diode forward voltage | V_{DSF} | $I_{DR} = 120\text{ A}, V_{GS} = 0\text{ V}$ | — | — | -1.2 | V |

Note 6: Ensure that the channel temperature does not exceed $175\text{ }^\circ\text{C}$.

7. Marking

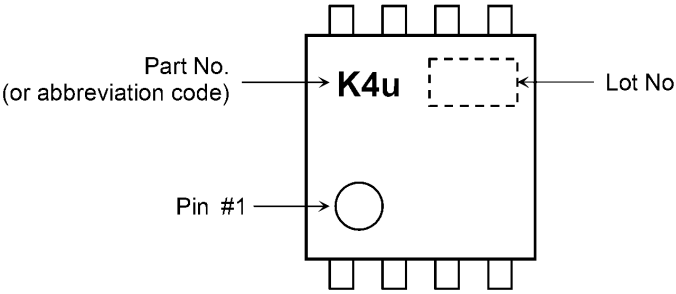


Fig. 7.1 Marking

8. Characteristics Curves (Note)

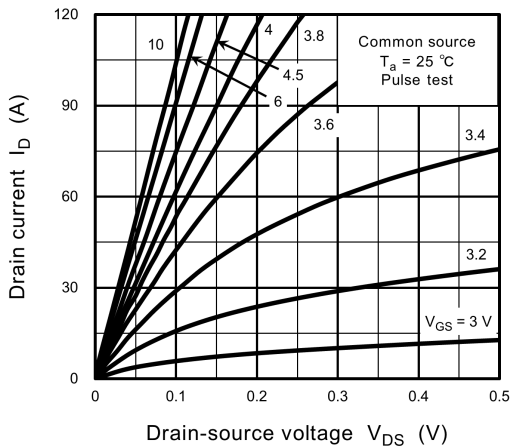


Fig. 8.1 $I_D - V_{DS}$

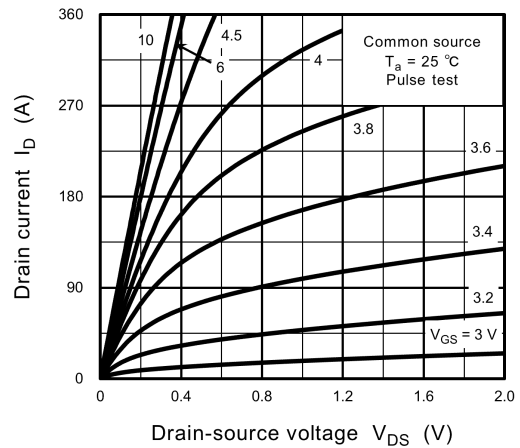


Fig. 8.2 $I_D - V_{DS}$

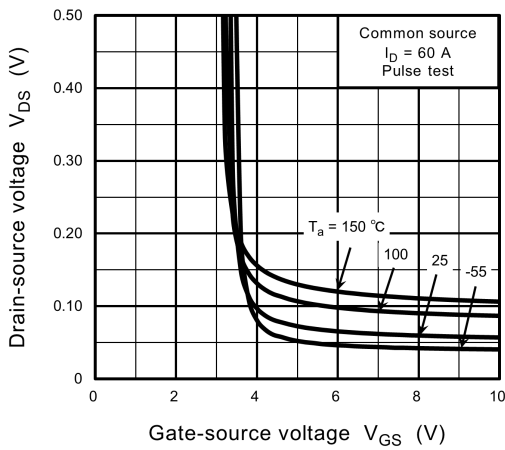


Fig. 8.3 $V_{DS} - V_{GS}$

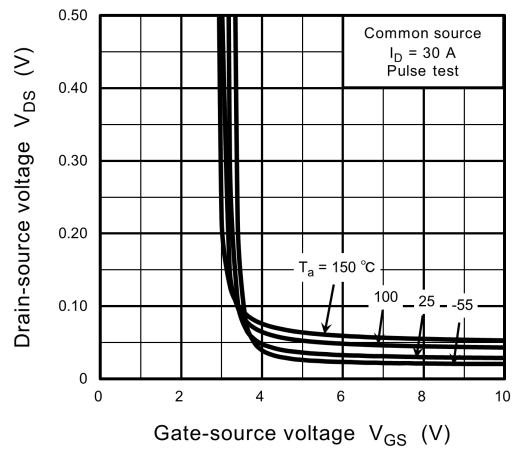


Fig. 8.4 $V_{DS} - V_{GS}$

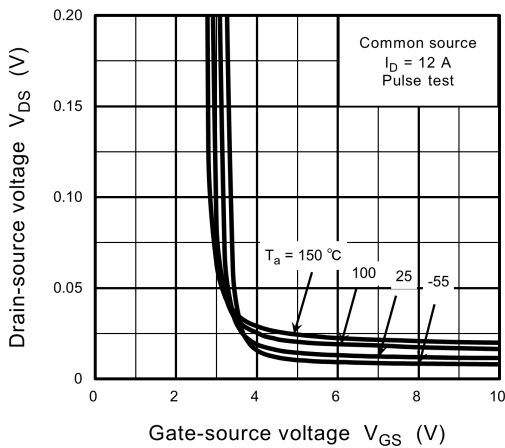


Fig. 8.5 $V_{DS} - V_{GS}$

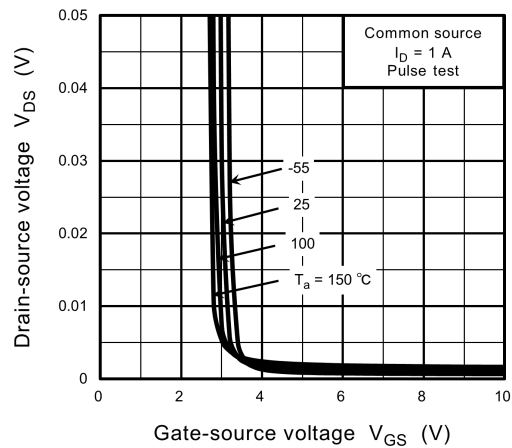


Fig. 8.6 $V_{DS} - V_{GS}$

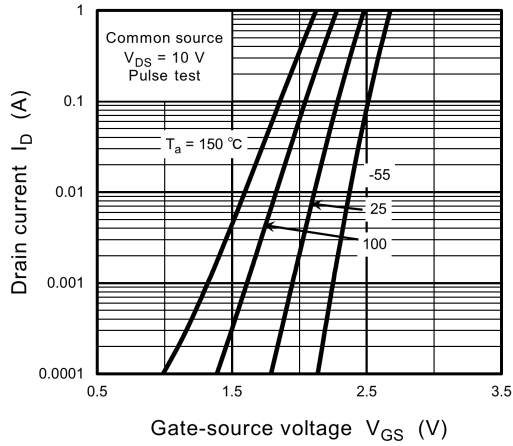


Fig. 8.7 $I_D - V_{GS}$

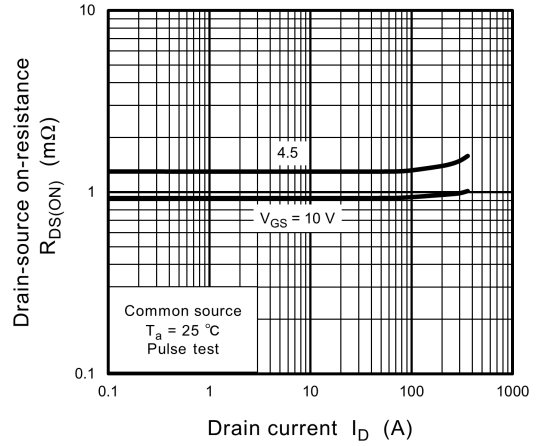


Fig. 8.8 $R_{DS(ON)} - I_D$

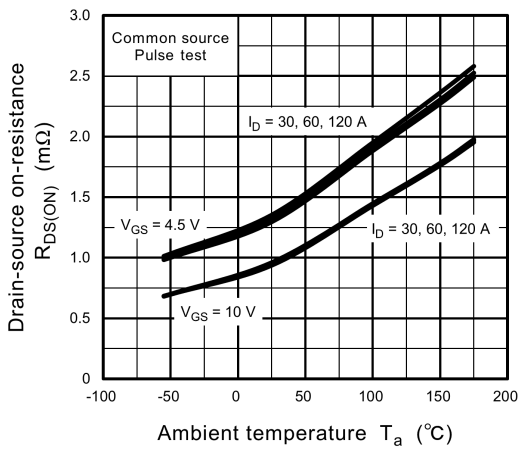


Fig. 8.9 $R_{DS(ON)} - T_a$

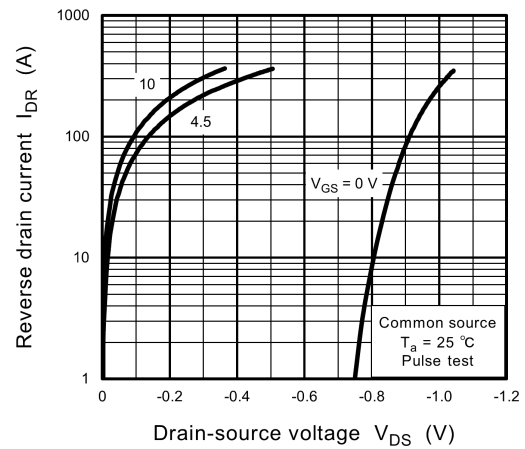


Fig. 8.10 $I_{DR} - V_{DS}$

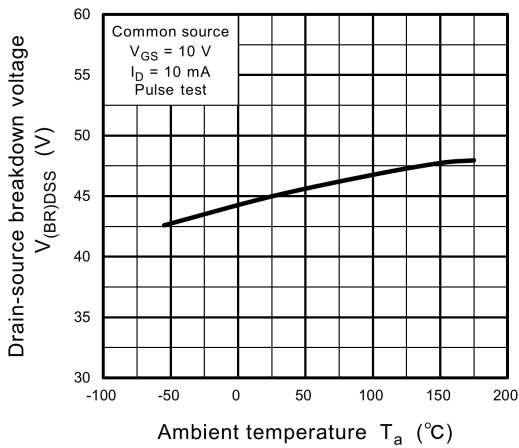


Fig. 8.11 $V_{(BR)DSS} - T_a$

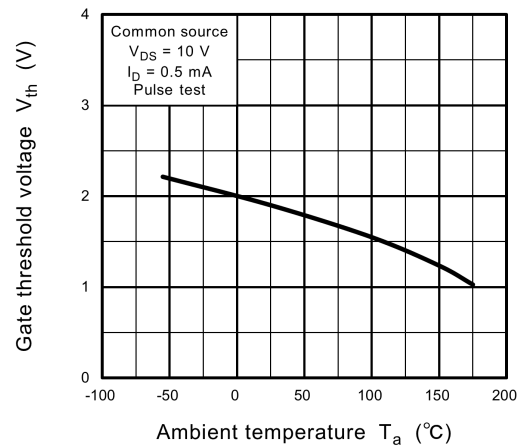


Fig. 8.12 $V_{th} - T_a$

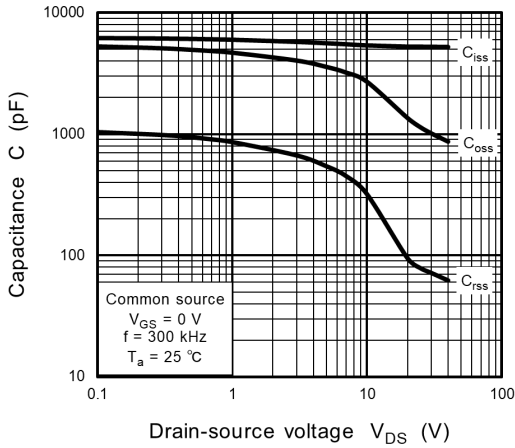


Fig. 8.13 Capacitance - V_{DS}

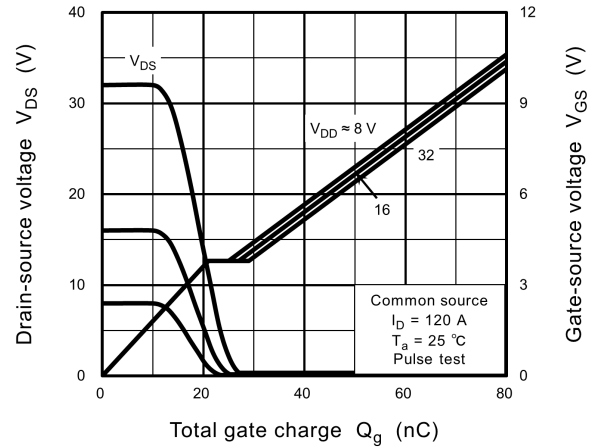
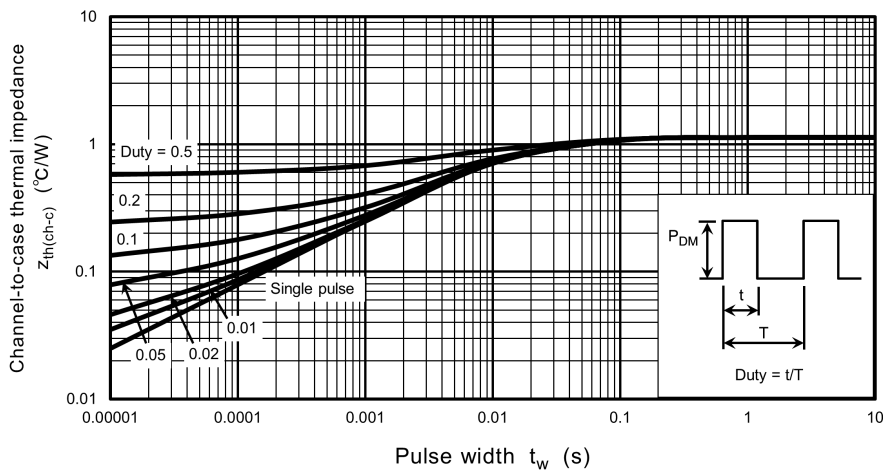
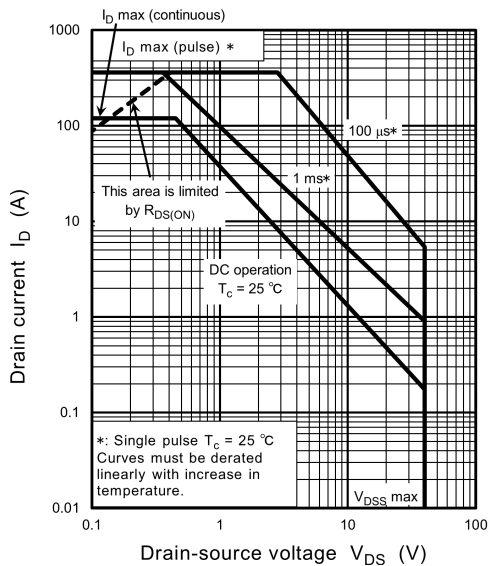


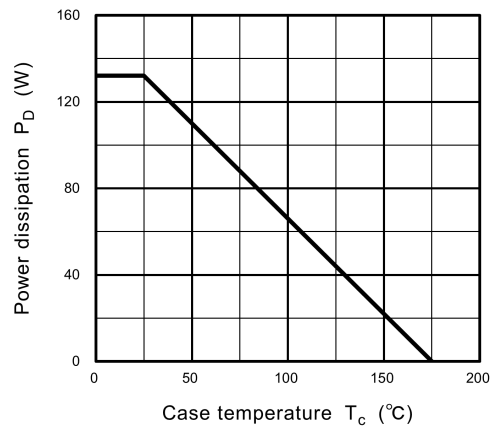
Fig. 8.14 Dynamic Input/Output Characteristics



**Fig. 8.15 $Z_{th(ch-c)} - t_w$
(Guaranteed Maximum)**



**Fig. 8.16 Safe Operating Area
(Guaranteed Maximum)**

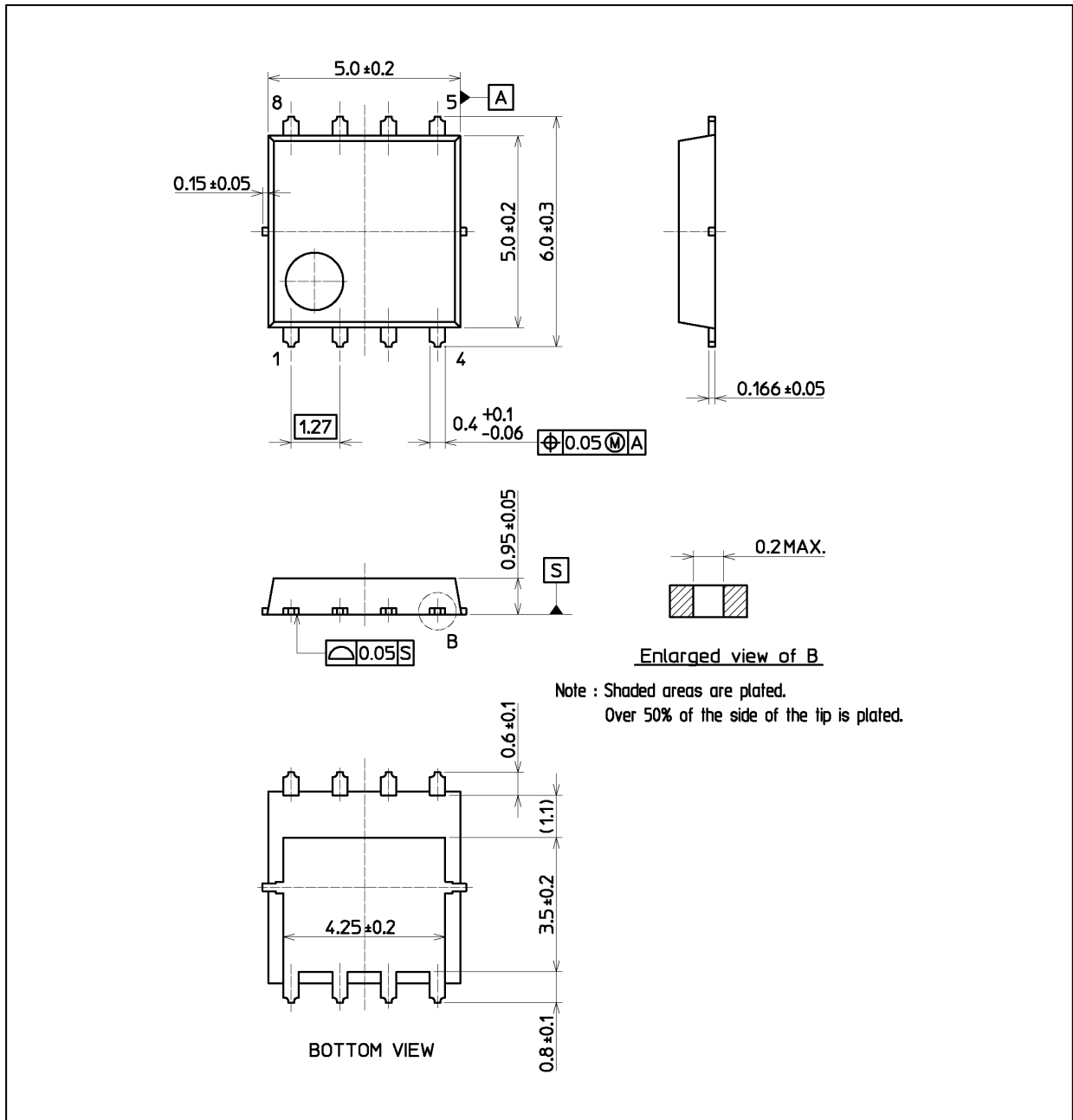


**Fig. 8.17 $P_D - T_c$
(Guaranteed Maximum)**

Note: The above characteristics V_{DS} are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.080 g (typ.)

| Package Name(s) |
|---------------------------|
| TOSHIBA: 2-5Q4A |
| Nickname: SOP Advance(WF) |

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